

COST 539 Action - ELENA

Programme and Book of Abstracts

4th Workshop

Fabrication, Properties & Applications of Electroceramic Nanostructures

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Programme and Book of Abstracts of 4th Workshop COST 539 Fabrication, Properties & Applications of Electroceramic Nanostructures

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Preface

In recent period t tailored innovative proce materials and to improve

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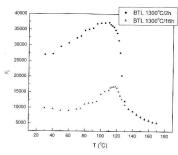
PROPERTIES OF LANTHANUM DOPED BARIUM TITANATE PRODUCED FROM NANOPOWDERS

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As a first discovered ferroelectric ceramic, barium titanate has become one of the most extensively investigated ceramic materials used in electronics. For many years, A- and B-site dopants have been used to modify the electrical properties of BaTiO₃. In this paper, barium titanate doped with 0.3 mol% of lanthanum and sintered at different sintering times was investigated. Doped barium titanate nanopowder was prepared by doping pure barium titanate starting from citrate solutions of all components: barium, titanium and lanthanum. Experimental procedure was given in detail in previous reports [1]. Obtained powders were pressed in to pellets and sintered at 1300 °C for 2 and 16h in air atmosphere. The formation of phase and crystal structure of BaTiO₃ was carried out by XRD analysis. Microstructural properties such as grain size distribution and morphology of sintered samples were determined using scanning electron microscope. Measurement of dielectric constant and dielectric losses was provided in the frequency range of 20 to 10⁶ Hz. The variation of the dielectric constant with temperature was measured in temperature interval from 20 to 180 °C.

The XRD analysis of doped barium titanate indicates the formation of tetragonal phase in samples sintered at both sintering times. Lanthanum has an influence on grain growth and shape of grains in doped barium titanate [2]. It was detected that the grain size also depends on sintering time. It can be notified the effect of lanthanum and sintering time on dielectric constant. Lanthanum also has influence on decreasing the Curie temperature of barium titanate. No frequency dependence of dielectric constant was detected.



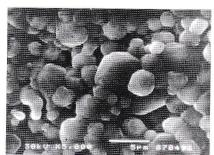


Fig.1. Dielectric constant vs. temperature and microstructure of barium titanate sintered sample

Refereces

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COST-P-14

RAMAN STUDY OF FERROELECTRIC BISMUTH LAYER-OXIDE ABi₄Ti₄O₁₅ PREPARED BY THE MECHANOCHEMICAL SYNTHESIS

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Ferroelectric materials have innumerable properties related to their spontaneous polarization, for instance, pyre- and piezoelectricity, which are used for various sensors and actuators [1]. BaBi₄Ti₄O₁₅ (BBT) is an n = 4 member of the Bi-layer structured ferroelectric oxide family (Aurivillius phase) [2]. Bi-layered structure ferroelectric material - bismutt titanate, Bi₄Ti₃O₁₂ (BIT) and barium-bismuth titanate, BaBi₄Ti₄O₁₅ (BBT) ceramic powders were prepared by mechanical synthesis possess. BaBi₄Ti₄O₁₅ was prepared from stoichicmetric quantities of barium titanate and bismuth titanate obtained via mechanochemical synthesis. Barium titanate, BaTiO3 has been synthesised from mixture of BaO and TiO2 and bismuth titanate, Bi₄Ti₃O₁₂ was prepared starting from Bi₂O₃ and TiO₂, commercially available. The reaction mechanism of BBT and the preparation and characteristics of BBT ceramic powders were studied using X-ray diffraction (XRD) and IR spectroscopy. The phonon modes have been studied by Raman spectroscopy. The Bi-layered perovskite structure of BBT ceramic forms at 1100 °C. Microstructure of Bi₄Ti₃O₁₂ is in accordance with the view that Bi₄Ti₃O₁₂ exhibits plate-like grains with thr average grain size increasing with the sintering temperature. It is evident that Ba2+ adition leads to the change in the microstructure development, particularly in the change of the average grain size and homogeneity of the grains of BaBi₄Ti₄O₁₅.

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- [2] Aurivillius B., Ark. Kemi 2 (1950) 519 (in English); Subbarao E.C., J. Am. Ceram. Soc. 45 (1962) 166.

CHARACTERIZATI PREPARED BY M

J.D. Bobić¹, B.D.

Institute for Muli Jozef S

Barium bismuth titanate layer-structure ferroelectric oxic preparation and properties of BB for high-temperature lead-free pronvolatile memories (Fe-RAM)

Barium-bismuth titanate BaTi₃O₁₂ and Bi₄Ti₃O₁₂ obtaine BaTi₃O₁₂ has been synthesised f starting from Bi₂O₃ and TiO₂, co carried by TG/DTA methods at powder mixture of BT and BIT appropriate temperature of sint 1100°C to 1140°C.

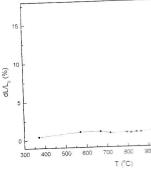


Fig. 1. Sintering curve of of BaTi₃O₁₂ and

Powder mixture of Ba 1120°C for 1h and the density formation of phase and crystal The microstructure and morph microscopy. Electrical property

Refereces

- [1] Miranda C., Costa M.E.V., (2001) 1303–1306.
- [2] Jannet D.B., Maaoui M.E., I

COST-P-15

CHARACTERIZATION OF BARIUM BISMUTH TITANATE PREPARED BY MECHANICAL ASSISTED SYNTHESIS

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Barium bismuth titanate (BaBi $_4$ Ti $_4$ O $_{15}$ - BBiT) is an n=4 member of the Bi-baselayer-structure ferroelectric oxide family (Aurivillius phase). A lot of aspects of the preparation and properties of BBiT remain unexplored, whereas being promising candidate for high-temperature lead-free piezoelectric device, memory application and ferroelectric nonvolatile memories (Fe-RAM) [1,2].

Barium-bismuth titanate BBiT was prepared from stoichiometric quantities of BaTi₃O₁₂ and Bi₄Ti₃O₁₂ obtained via mechanically assisted synthesis in planetary ball mill. BaTi₃O₁₂ has been synthesised from mixture of BaO and TiO₂ and Bi₄Ti₃O₁₂ was prepared starting from Bi₂O₃ and TiO₂, commercially available. Characterization of this powder was carried by TG/DTA methods and measuring particle size distribution. Sintering curve of powder mixture of BT and BIT is presented on Fig. 1. This result is used to determinate appropriate temperature of sintering. The temperature range of sintering is narrow, from 1100°C to 1140°C.

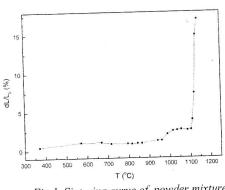


Fig. 1. Sintering curve of powder mixture of BaTi₃O₁₂ and Bi₄Ti₃O₁₂

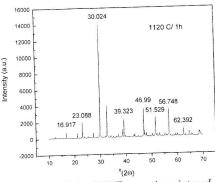


Fig. 2. XRD of BBiT ceramics sintered at 1120°C for 1h

Powder mixture of BaTi₃O₁₂ and Bi₄Ti₃O₁₂ was sintered at 1100°C, 1110°C and 1120°C for 1h and the density of sample is about 74,5%, 87,5%, 90.73%, respectively. The formation of phase and crystal structure BBiT were approved using X-ray analysis (Fig. 2). The microstructure and morphology of samples were investigated using scanning electron microscopy. Electrical properties of BBiT ceramics was also carried out.

- [1] Miranda C., Costa M.E.V., Avdeeev M., Kholkin A.L., Baptista J.L., J. Eur. Ceram. Soc., 21 (2001) 1303-1306.
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